

🦒 Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Report No: CCISE171206906

FCC REPORT

Applicant: SHENZHEN COOTEL FONE TECHNOLOGY CO.,LTD

Address of Applicant: No.311, 3rd Floor, Langfeng Building, No.2, Kefa Road,

Nanshan District, Shenzhen, China

Equipment Under Test (EUT)

Product Name: Smart phone

Model No.: C8

Trade mark: CooTel

FCC ID: 2AHS2-C8

FCC CFR Title 47 Part 2

Applicable standards: FCC CFR Title 47 Part 27 Subpart L

Date of sample receipt: 18 Dec., 2017

Date of Test: 18 Dec., 2017 to 16 Jan., 2018

Date of report issued: 17 Jan., 2018

Test Result: PASS*

Authorized Signature:



Bruce Zhang Laboratory Manager

This report details the results of the testing carried out on one sample. The results contained in this test report do not relate to other samples of the same product and does not permit the use of the CCIS product certification mark. The manufacturer should ensure that all products in series production are in conformity with the product sample detailed in this report.

This report may only be reproduced and distributed in full. If the product in this report is used in any configuration other than that detailed in the report, the manufacturer must ensure the new system complies with all relevant standards.

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^{*}In the configuration tested, the EUT complied with the standards specified above.





2. Version

Version No.	Date	Description
00	17 Jan., 2018	Original

Test Engineer

Reviewed by: Date: 17 Jan., 2018

Project Engineer



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4. Test Summary

Test Items	Section in CFR 47	Result
DE Evacura (SAB)	Part 1.1307	Passed
RF Exposure (SAR)	Part 2.1093	(Please refer to SAR Report)
DE Output Dower	Part 2.1046	Pass
RF Output Power	Part 27.50 (d)(4)	F d55
Peak-to-Average Ratio	Part 27.50(d)(5)	Pass
Modulation Characteristics	Part 2.1047	Pass
000/ 9 26 dB Occupied Bandwidth	Part 2.1049	Page
99% & -26 dB Occupied Bandwidth	Part 27.53(h)	Pass
Spurious Emissions at Antonna Torminal	Part 2.1051	Pass
Spurious Emissions at Antenna Terminal	Part 27.53 (h)	Pass
Field Strength of Spurious Radiation	Part 2.1053	Pass
rield Strength of Spurious Radiation	Part 27.53 (h)	r ass
Out of band emission, Band Edge	Part 27.53 (h)	Pass
Fraguenay etability va tamperatura	Part 27.54	Door
Frequency stability vs. temperature	Part 2.1055(a)(1)(b)	Pass
Fraguency stability vs. voltage	Part 27.54	Pass
Frequency stability vs. voltage	Part 2.1055(d)(2)	F455
Pass: The EUT complies with the essential re	equirements in the standard.	



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5. General Information

5.1 Client Information

Applicant:	SHENZHEN COOTEL FONE TECHNOLOGY CO.,LTD	
Address:	No.311, 3rd Floor, Langfeng Building, No.2, Kefa Road, Nanshan District, Shenzhen, China	
Manufacturer/Factory:	SHENZHEN COOTEL FONE TECHNOLOGY CO.,LTD	
Address:	No.311, 3rd Floor, Langfeng Building, No.2, Kefa Road, Nanshan District, Shenzhen, China	

5.2 General Description of E.U.T.

Product Name:	Smart phone
Model No.:	C8
Operation Frequency range:	LTE Band 4: TX: 1710MHz-1755MHz, RX: 2110MHz-2155MHz
Modulation type:	QPSK, 16QAM
Antenna type:	Internal Antenna
Antenna gain:	LTE Band 4: 0.7 dBi
Power supply:	Rechargeable Li-ion Battery DC3.85V-2700mAh
AC adapter:	Model: UF22P1501 Input: AC100-240V 50/60Hz 500mA Output: DC 5.0V, 2.1 A DC 9.0V, 1.67A DC 12.0V, 1.25A





Operation Frequency List:

Operation Frequency List	t:			
LTE Band	4 (1.4MHz)	LTE Band 4 (3MHz)		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
19957	1710.70	19965	1711.50	
19958	1710.80	19966	1711.60	
20174	1732.40	20174	1732.40	
20175	1732.50	20175	1732.50	
20176	1732.60	20176	1732.60	
20392	1754.20	20384	1753.40	
20393	1754.30	20385	1753.50	
LTE Band	d 4 (5MHz)	LTE Band	4 (10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
19975	1712.50	20000	1715.00	
19976	1712.60	20001	1715.10	
20174	1732.40	20174	1732.40	
20175	1732.50	20175	1732.50	
20176	1732.60	20176	1732.60	
20374	20374 1752.40		1749.90	
20375	1752.50	20350	1750.00	
LTE Band	4 (15MHz)	LTE Band 4 (20MHz)		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
20025	1717.50	20050	1720.00	
20026	1717.60	20051	1720.10	
20174	1732.40	20174	1732.40	
20175	1732.50	20175	1732.50	
20176	1732.60	20176	1732.60	
20324	1747.40	20299	1744.90	
20325	1747.50	20300	1745.00	

Regards to the operating frequency range, the lowest frequency, the middle frequency, and the highest frequency of channel were selected to perform the test, and the selected channels as below:





LTE	Band 4 (1.4MI	Hz)	LTE Band 4 (3MHz)		
Channel:		Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	19957	1710.70	Lowest channel	19965	1711.50
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20393	1754.30	Highest channel	20385	1753.50
LTI	E Band 4 (5MH	lz)	LTE Band 4 (10MHz)		
Channel		Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	19975	1712.50	Lowest channel	20000	1715.00
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20375	1752.50	Highest channel	20350	1750.00
LTE Band 4 (15MHz)			LTE Band 4 (20MHz)		
Channel		Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	20025	1717.50	Lowest channel	20050	1720.00
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20325	1747.50	Highest channel	20300	1745.00



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5.3 Test environment and mode

Operating Environment:		
Normal: 15°C ~ 35°C, Extreme: -30°C ~ +50°C		
20 % ~ 75 % RH		
1008 mbar		
Nominal: 3.85 Vdc, Extreme: Low 3.5 Vdc, High 4.35 Vdc		
Keep the EUT communication with simulated station in QPSK mode		
Keep the EUT communication with simulated station in 16-QAM mode		

Remark: The EUT has been tested under continuous transmitting mode. Channel Low, Mid and High for each type band with rated data rate were chosen for full testing. The field strength of spurious radiation emission was measured as EUT stand-up position (H mode) and lie down position (E1, E2 mode) for these modes with power adaptor, earphone and Data cable. Just the worst case position (H mode) shown in report.

5.4 Description of Support Units

Test Equipment	Manufacturer	Model No.	Serial No.	
Simulated Station	Anritsu	MT8820C	6201026545	

5.5 Measurement Uncertainty

Parameters	Expanded Uncertainty	
Radiated Emission (9kHz ~ 30MHz)	4.24 dB (k=2)	
Radiated Emission (30MHz ~ 1000MHz)	4.35 dB (k=2)	
Radiated Emission (1GHz ~ 18GHz)	4.44 dB (k=2)	
Radiated Emission (18GHz ~ 26.5GHz)	4.56 dB (k=2)	

5.6 Related Submittal(s) / Grant (s)

This is an original grant, no related submittals and grants.

5.7 Laboratory Facility

The test facility is recognized, certified, or accredited by the following organizations:

• FCC - Registration No.: 727551

Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been accredited as a testing laboratory by FCC (Federal Communications Commission). The Registration No. is 727551.

• IC - Registration No.: 10106A-1

The 3m Semi-anechoic chamber of Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been Registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 10106A-1.

CNAS - Registration No.: CNAS L6048

Shenzhen Zhongjian Nanfang Testing Co., Ltd. is accredited to ISO/IEC 17025:2005 General Requirements for the Competence of Testing and Calibration laboratories for the competence of testing. The Registration No. is CNAS L6048.

A2LA - Registration No.: 4346.01

This laboratory is accredited in accordance with the recognized International Standard ISO/IEC 17025:2005 General requirements for the competence of testing and calibration laboratories. The test scope can be found as below link: https://portal.a2la.org/scopepdf/4346-01.pdf

Shenzhen Zhongjian Nanfang Testing Co., Ltd.
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5.8 Laboratory Location

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Address: No. B-C, 1/F., Building 2, Laodong No.2 Industrial Park, Xixiang Road,

Bao'an District, Shenzhen, Guangdong, China Tel: +86-755-23118282, Fax: +86-755-23116366

Email: info@ccis-cb.com, Website: http://www.ccis-cb.com

5.9 Test Instruments list

Test Equipment	Manufacturer	Model No.	Serial No.	Cal. Date (mm-dd-yy)	Cal. Due date (mm-dd-yy)
3m SAC	SAEMC	9m*6m*6m	966	07-22-2017	07-21-2020
BiConiLog Antenna	SCHWARZBECK	VULB9163	497	02-25-2017	02-24-2018
Biconical Antenna	SCHWARZBECK	VUBA9117	359	06-22-2017	06-21-2018
Horn Antenna	SCHWARZBECK	BBHA9120D	916	02-25-2017	02-24-2018
Horn Antenna	SCHWARZBECK	BBHA9120D	1805	02-25-2017	02-24-2018
EMI Test Software	AUDIX	E3	6.110919b	N/A	N/A
Pre-amplifier	HP	8447D	2944A09358	02-25-2017	02-24-2018
Pre-amplifier	CD	PAP-1G18	11804	02-25-2017	02-24-2018
Spectrum analyzer	Rohde & Schwarz	FSP30	101454	02-25-2017	02-24-2018
EMI Test Receiver	Rohde & Schwarz	ESRP7	101070	02-25-2017	02-24-2018
Spectrum Analyzer	Agilent	N9020A	MY50510123	10-29-2017	10-28- 2018
Signal Generator	Rohde & Schwarz	SMX	835454/016	02-25-2017	02-24- 2018
Signal Generator	R&S	SMR20	1008100050	02-25-2017	02-24-2018
RF Switch Unit	MWRFTEST	MW200	N/A	N/A	N/A
Cable	ZDECL	Z108-NJ-NJ-81	1608458	02-25-2017	02-24-2018
Cable	MICRO-COAX	MFR64639	K10742-5	02-25-2017	02-24-2018
Cable	SUHNER	SUCOFLEX100	58193/4PE	02-25-2017	02-24-2018
DC Power Supply	XinNuoEr	WYK-10020K	1409050110020	10-31-2017	10-30-2018
Temperature Humidity Chamber	HengPu	HPGDS-500	20140828008	09-24-2017	09-23-2018
Simulated Station	Rohde & Schwarz	CMW500	140493	06-24-2017	06-23-2018



6. Test results

6.1 Conducted Output Power

Test Requirement:	Part 27.50(d)(4),		
Test Method:	ANSI/TIA-603-D 2010		
Limit:	LTE Band 4: 1W		
Test Setup:	System simulator ATT EUT		
Test Procedure:	The transmitter output was connected to a calibrated attenuator, the other end of which was connected to the CMW500. Transmitter output power was read off in dBm.		
Test Instruments:	Refer to section 5.9 for details		
Test mode:	Refer to section 5.3 for details		
Test results:	Passed		





Measurement Data:

Measureme			RB Size		Average Power (dBm)		
LTE Band	Bandwidth	Modulation		RB Offset	19957	20175	20393
	(MHz)	Modulation			1710.7MHz	1732.5MHz	1754.3MHz
			1	0	22.98	22.75	22.89
			1	2	23.17	22.83	23.23
			1	5	23.04	22.80	23.31
		QPSK	3	0	23.18	23.07	23.25
		QI SIX	3	1	23.15	23.08	23.15
			3	2	23.17	22.98	23.04
			6	0	22.25	22.56	22.21
4	1.4		1	0	22.06	21.75	22.15
			1	2	22.16	21.65	22.06
			1	5	21.75	21.36	21.35
		16QAM	3	0	22.09	21.95	21.84
		100,111	3	1	22.06	21.74	22.13
			3	2	22.24	21.83	22.41
			6	0	21.21	20.98	21.13
						erage Power (di	
LTE Band	Bandwidth	Modulation	RB Size	RB Offset	19965	20175	20385
LIL Dand	(MHz)	Wiodulation	IND SIZE		1711.5MHz	1732.5MHz	1753.5MHz
			1	0	22.85	22.89	22.85
			1	7	22.89	22.68	22.86
			1	14	22.74	22.63	23.01
		OBSK	8			22.03	
		QPSK		0	21.98		22.05
			<u>8</u> 8	7	22.17	21.86	22.14
			15	0	21.92	21.95	21.99
4	3				22.01 22.12	21.86 22.21	21.06
			1	7			21.80
			1	14	21.86	21.45	21.84
		16OAM	8	0	21.39	21.53	21.89
		16QAM			20.89	20.84	20.86
			8	4	20.89	20.78	20.78
			8	7	20.82	20.83	20.96
			15	0	20.84	20.72	20.92
LTE Day	Bandwidth (MHz)	Modulation	RB Size	RB Offset	Average Power (dBm)		
LTE Band					19975	20175	20375
					1712.5MHz	1732.5MHz	1752.5MHz
	5	QPSK	1	0	22.76	22.75	23.45
			1	12	22.89	22.56	23.26
			1	24	22.74	22.39	23.53
			12	0	21.78	22.58	22.74
4			12	6	21.90	22.42	22.36
			12	11	21.79	22.26	22.35
			25	0	21.78	22.43	22.45
		16QAM	1	0	21.20	22.21	22.82
			1	12	21.85	21.99	22.46
			1	24	21.50	21.06	21.74
			12	0	20.56	21.22	21.42
			12	6	20.71	21.45	21.57
			12	11	20.65	20.95	21.42
			25	0	20.63	21.03	21.43





					Average Power (dRm)			
LTE Band	Bandwidth	Modulation	RB Size	RB Offset	20000	Average Power (dBm)		
	(MHz)			RB Offset		20175	20350	
			1	0	1715.0MHz	1732.5MHz	1750.0MHz	
			1	0	23.45	23.51	23.16	
			1	24	23.05	23.30	23.45	
			1	49	23.15	23.41	23.14	
		QPSK	25	0	22.57	22.56	22.78	
			25	12	22.63	22.68	22.89	
			25	24	22.51	22.39	22.95	
4	10		50	0	22.45	22.50	22.45	
7	10		1	0	22.35	22.14	22.42	
			1	24	22.65	22.52	22.45	
			1	49	21.96	22.03	22.31	
		16QAM	25	0	21.64	21.45	21.58	
			25	12	21.51	21.68	21.68	
			25	24	21.43	21.31	21.63	
			50	0	21.40	21.45	21.37	
	_					Average Power (dBm)		
LTE Band	Bandwidth	Modulation	RB Size	RB Offset	20025	20175	20325	
212 24114	(MHz)	Modulation	112 0.20	112 011001	1717.5MHz	1732.5MHz	1747.5MHz	
			1	0	23.51	23.52	23.12	
			1	37	23.14	23.14	23.04	
			1	74	23.25	23.45	23.16	
		QPSK	<u>-</u>					
		Q CON	36	0	22.85	22.78	22.72	
			36	16	22.56	22.71	22.59	
			36	35	22.53	22.06	22.83	
4	15		75	0	22.45	22.54	22.72	
			1	0	23.12	22.84	22.30	
			1	37	23.14	22.73	22.42	
		460	1	74	21.78	21.98	22.20	
		16QAM	36	0	21.45	21.43	21.56	
			36	16	21.71	21.54	21.70	
			36	35	21.49	21.26	21.86	
			75	0	21.51	21.50	21.52	
	Bandwidth (MHz)	Modulation			Average Power (dBm)			
LTE Band			RB Size	RB Offset	20050	20175	20300	
					1720.0MHz	1732.5MHz	1745.0MHz	
			1	0	23.41	23.54	23.54	
	20	QPSK	1	49	23.51	23.43	23.45	
			1	99	23.34	23.35	23.56	
			50	0	22.78	22.72	22.82	
			50	24	22.57	22.86	22.65	
			50	49	22.34	22.41	22.71	
			100	0	22.54	22.48	22.62	
4		16QAM	1	0	22.82	22.56	22.68	
			1	49	21.98	22.67	22.24	
			1	99	22.14	22.27	22.43	
			50	0	21.42	21.64	21.45	
			50	24	21.85	21.82	21.58	
			50	49	21.65	21.02	21.59	
			100	0	21.50	21.35	21.48	





6.2 Peak-to-Average Ratio

Test Requirement:	Part 27.50(d)(5)
Test Method:	ANSI/TIA-603-D 2010
Limit:	The peak-to-average ratio (PAR) of the transmission may not exceed 13 dB.
Test Setup:	System simulator Spectrum Analyzer Spectrum Analyzer
Test Procedure:	 The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation. Set the CCDF option in spectrum analyzer, RBW ≥ OBW, Set the EUT working in highest power level, measured and recorded the 0.1% as PAPR level. Repeat step 1~3 at other frequency and modulations.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed

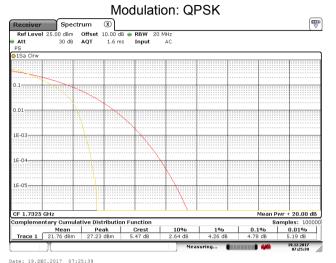


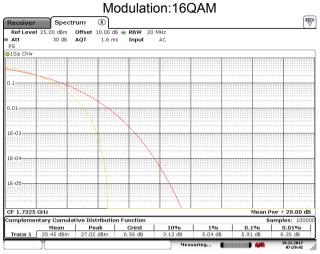


Measurement Data:

Test plots as below:

LTE Band 4 Middle channel





Date: 19.DEC.2017 07:29:42





6.3 Occupy Bandwidth

1 7	
Test Requirement:	Part 27.53(h),
Test Method:	ANSI/TIA-603-D 2010
Test Setup:	System simulator Spectrum Analyzer
Test Procedure:	 The EUT's output RF connector was connected with a short cable to the spectrum analyzer RBW was set to about 1% ~ 5% of emission BW, VBW= 3 times RBW. -26dBc display line was placed on the screen (or 99% bandwidth), the occupied bandwidth is the delta frequency between the two points where the display line intersects the signal trace.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data:

LTE Band 4 part:

LTE Band 4 par	<u>'t:</u>				
Bandwidth	Channel	Frequency(MHz)	Modulation	99% OBW (kHz)	-26dBcEBW (kHz)
1.4MHz	19957	1710.7	16QAM	1092	1302
	19957	1710.7	QPSK	1098	1308
	20175	1732.5	16QAM	1104	1278
	20173	1732.5	QPSK	1099	1296
	20393	1754.3	16QAM	1104	1320
			QPSK	1104	1290
	10065	1711.5	16QAM	2736	3024
	19965		QPSK	2736	3060
3MHz	20175	1732.5	16QAM	2736	3012
SIVITZ	20175		QPSK	2736	3072
	20205	4750.5	16QAM	2736	3036
	20385	1750.5	QPSK	2736	3060
	10075	4740 F	16QAM	4480	4900
	19975	1712.5	QPSK	4520	4960
ENALL-	20475	4700 F	16QAM	4500	4860
5MHz	20175	1732.5	QPSK	4500	4940
	20375	1752.5	16QAM	4500	4900
			QPSK	4520	4960
	20000	1715.0	16QAM	9040	10040
			QPSK	9080	10080
400411-	20175	1732.5	16QAM	9040	10040
10MHz			QPSK	9040	10120
	20350	1750.0	16QAM	9040	10080
			QPSK	9080	10280
	20025	1717.5	16QAM	13500	14640
			QPSK	13560	14760
15MHz	20175	1732.5	16QAM	13440	14760
			QPSK	13500	14640
	20325	1747.5	16QAM	13500	14580
			QPSK	13500	14820
	20050	1720.0	16QAM	18000	19360
			QPSK	17920	19520
201411-	20175	1732.5	16QAM	17840	19120
20MHz			QPSK	17920	19360
	20300	1745.0	16QAM	17920	19360
			QPSK	18000	19440

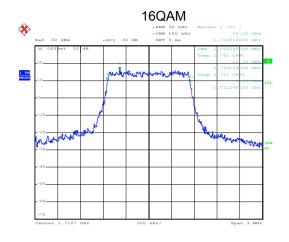


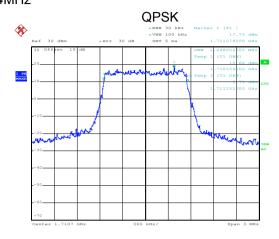


Test plot as follows:

LTE Band 4 part

99% Occupy bandwidth BW: 1.4MHz

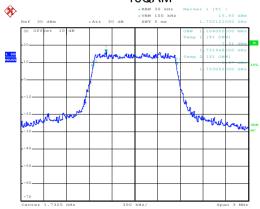


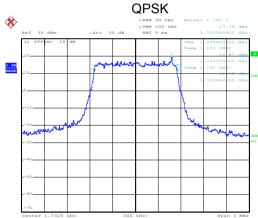


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Date: 18.DEC.2017 15:49:36

Lowest channel 16QAM -ARM 30 bits Market 1 [T1]



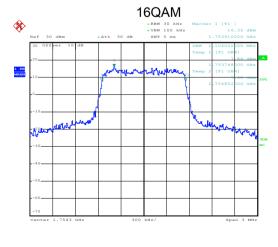


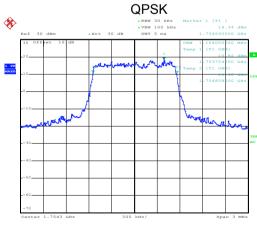
Date: 18.DEC.2017 15:50:16

Date: 18.DEC.2017 15:52:01

Date: 18.DEC.2017 15:50:11

Middle channel



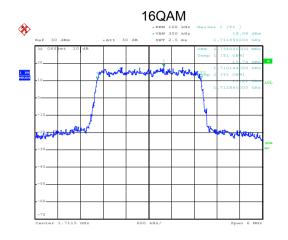


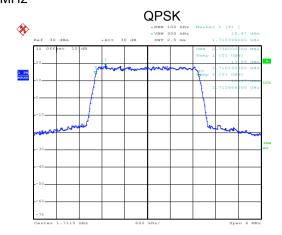
Date: 18.DEC.2017 15:51:56

Highest channel



99% Occupy bandwidth BW: 3MHz



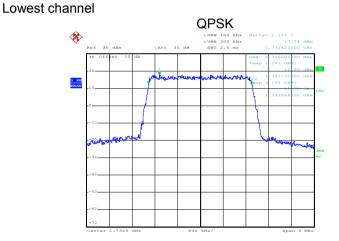


Date: 18.DEC.2017 15:53:22

Date: 18.DEC.2017 15:53:18

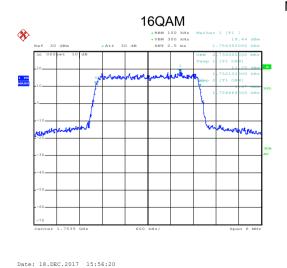
Date: 18.DEC.2017 15:54:16

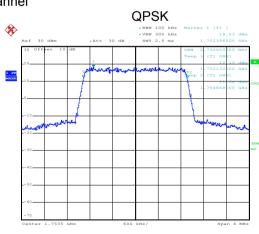
REW 100 kHz Macker 1 [T1] * YOW 300 kHz 17.49 dmm * ARE 30 dm * ARE 30 dm SWT 2.5 mm 1.732736000 sHz 33 Off PE 10 dm - ARE 30 dm SWT 2.5 mm 1.7323736000 sHz - CON 1.73132200 cms 1.73132200 cms 1.7333868000 cms - CON 1.7333868000 cms - CON 1.7333868000 cms - CON 1.7333868000 cms - CON 1.733868000 cms



Date: 18.DEC.2017 15:54:20

Middle channel





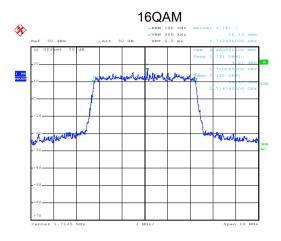
liada a at a la a a a a l

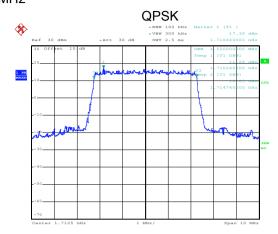
Date: 18.DEC.2017 15:56:12

Highest channel



99% Occupy bandwidth BW: 5MHz



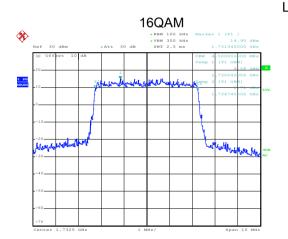


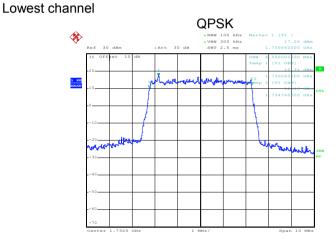
Date: 18.DEC.2017 15:57:23

Date: 18.DEC.2017 15:57:18

Date: 18.DEC.2017 15:58:09

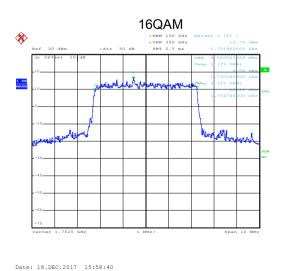
Date: 18.DEC.2017 15:58:35

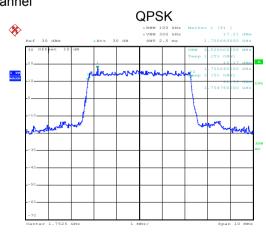




Date: 18.DEC.2017 15:58:13

Middle channel

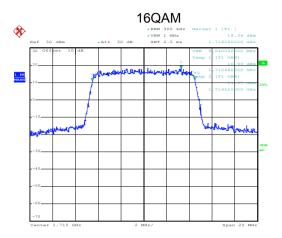


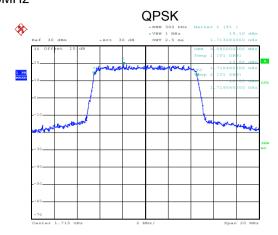


Highest channel



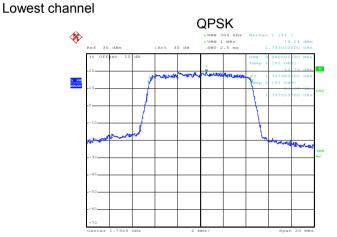
99% Occupy bandwidth BW: 10MHz





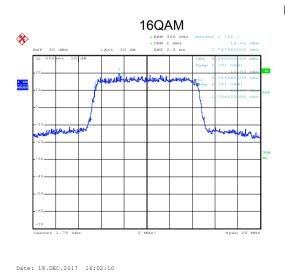
Date: 18.DEC.2017 16:01:00

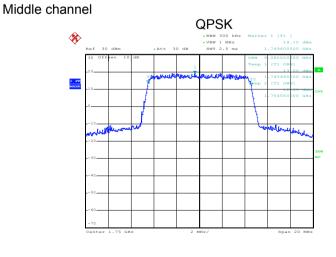
Date: 18.DEC.2017 16:00:56



Date: 18.DEC.2017 16:01:22

Date: 18.DEC.2017 16:01:17



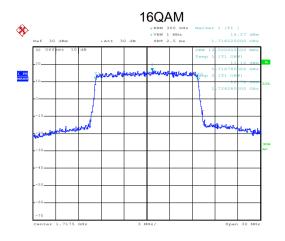


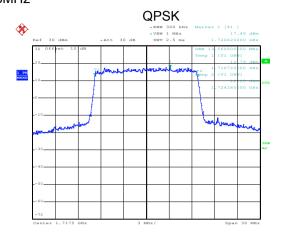
Highest channel

Date: 18.DEC.2017 16:02:06



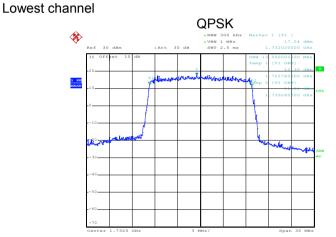
99% Occupy bandwidth BW: 15MHz





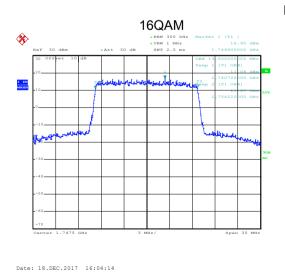
Date: 18.DEC.2017 16:02:51

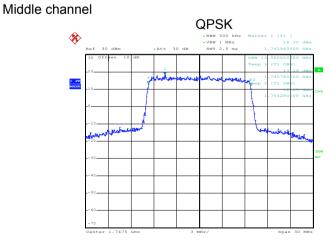
Date: 18.DEC.2017 16:02:46



Date: 18.DEC.2017 16:03:45

Date: 18.DEC.2017 16:03:39



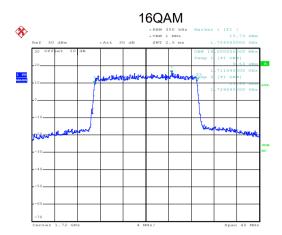


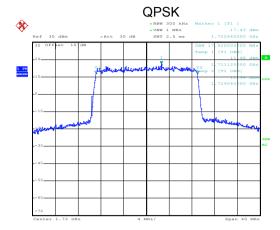
Highest channel

Date: 18.DEC.2017 16:04:09



99% Occupy bandwidth BW: 20MHz

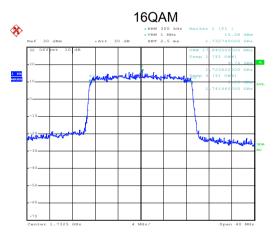


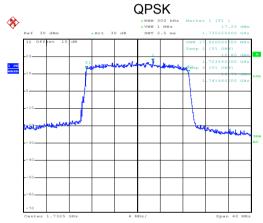


Date: 18.DEC.2017 16:05:30

Date: 18.DEC.2017 16:05:23

Lowest channel



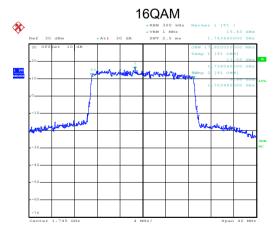


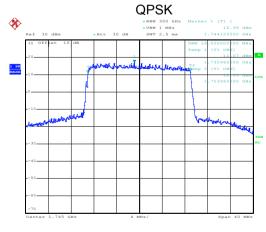
Date: 18.DEC.2017 16:05:56

Date: 18.DEC.2017 16:07:52

Date: 18.DEC.2017 16:05:50

Middle channel



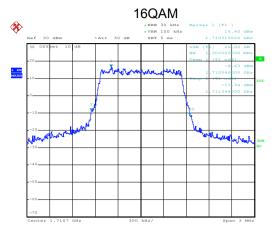


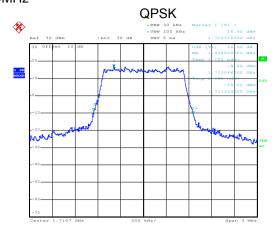
Date: 18.DEC.2017 16:07:48

Highest channel



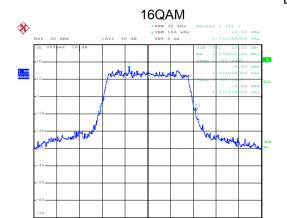
-26dBc bandwidth BW: 1.4MHz

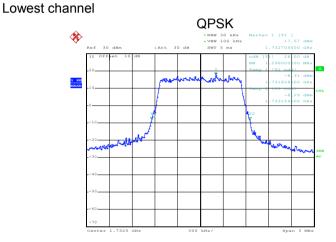




Date: 18.DEC.2017 15:49:25

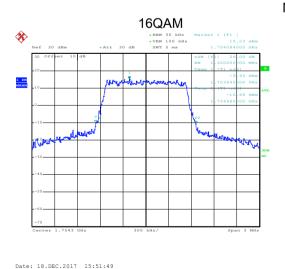
Date: 18.DEC.2017 15:49:20

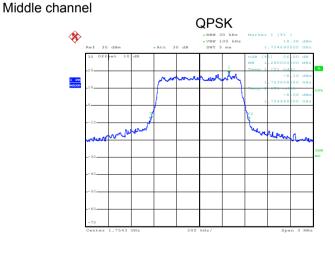




Date: 18.DEC.2017 15:51:23

Date: 18.DEC.2017 15:51:18

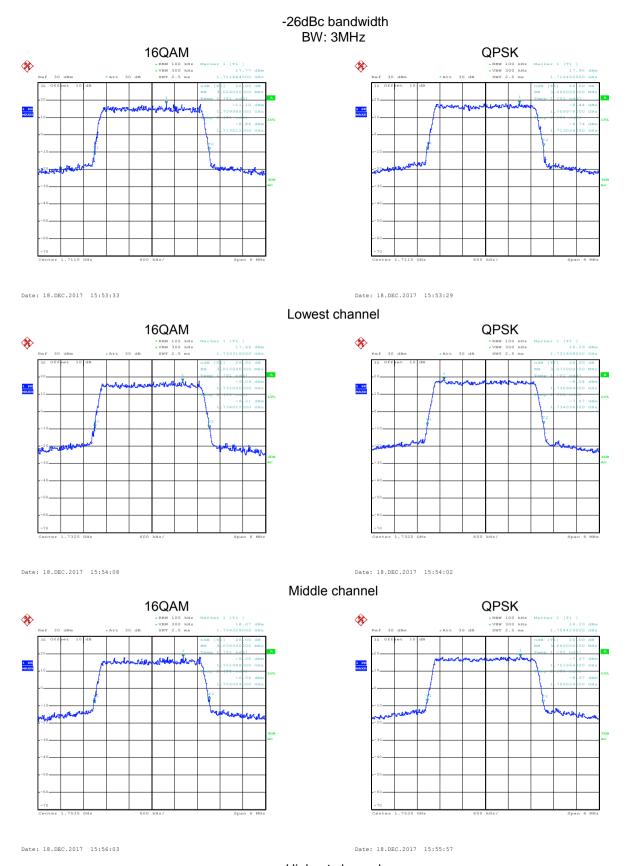




Date: 18.DEC.2017 15:51:45

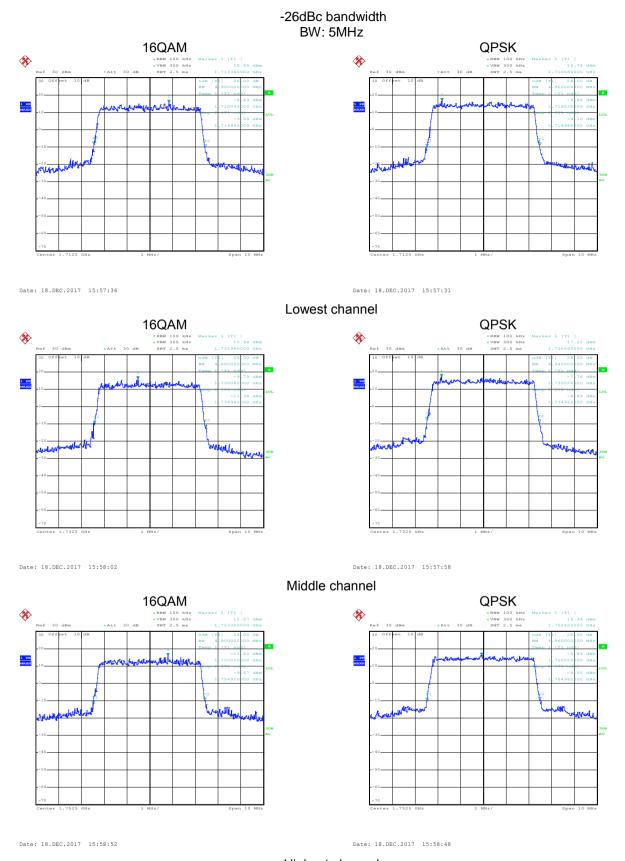
Highest channel





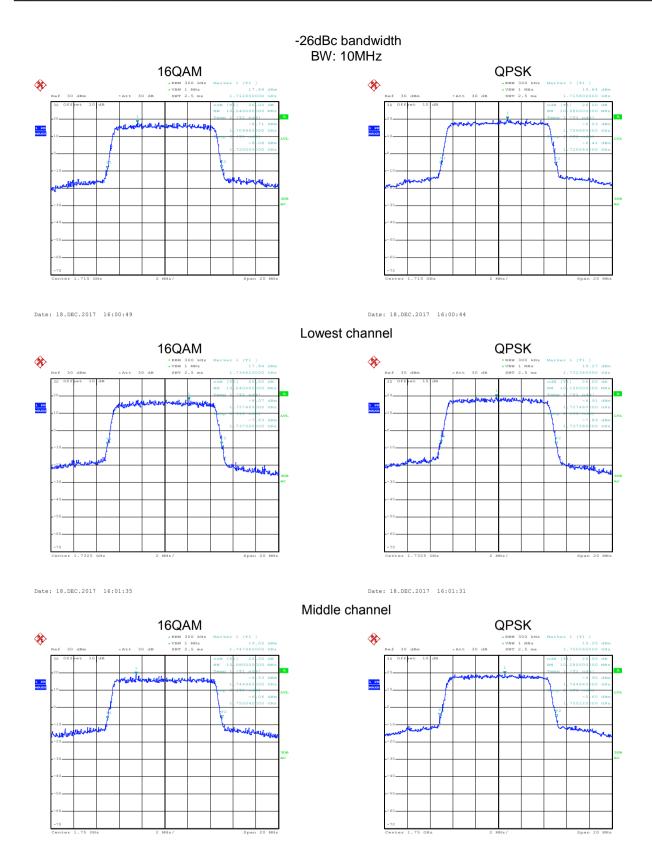
Highest channel





Highest channel



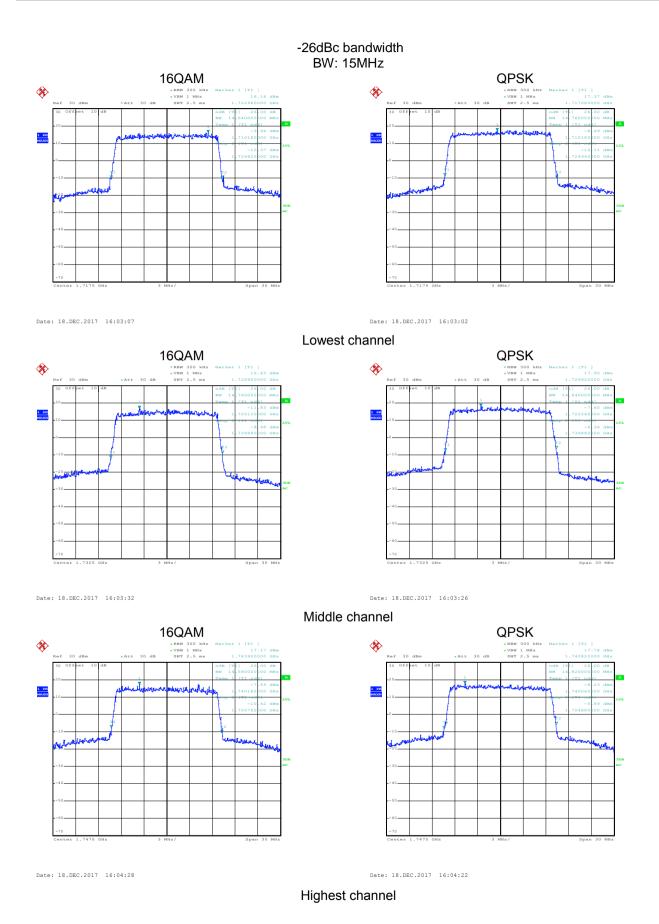


Highest channel

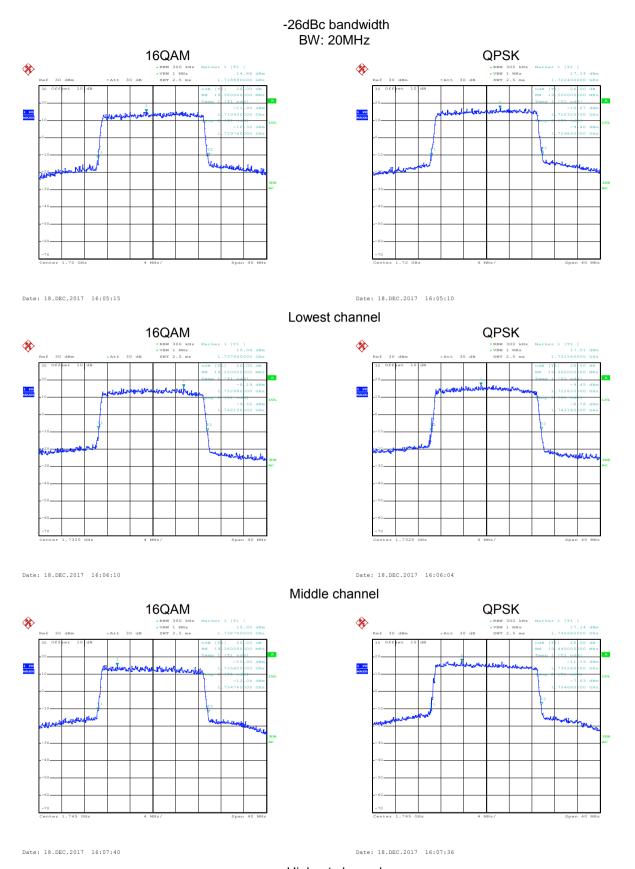
Date: 18.DEC.2017 16:01:54

Date: 18.DEC.2017 16:01:59









Highest channel





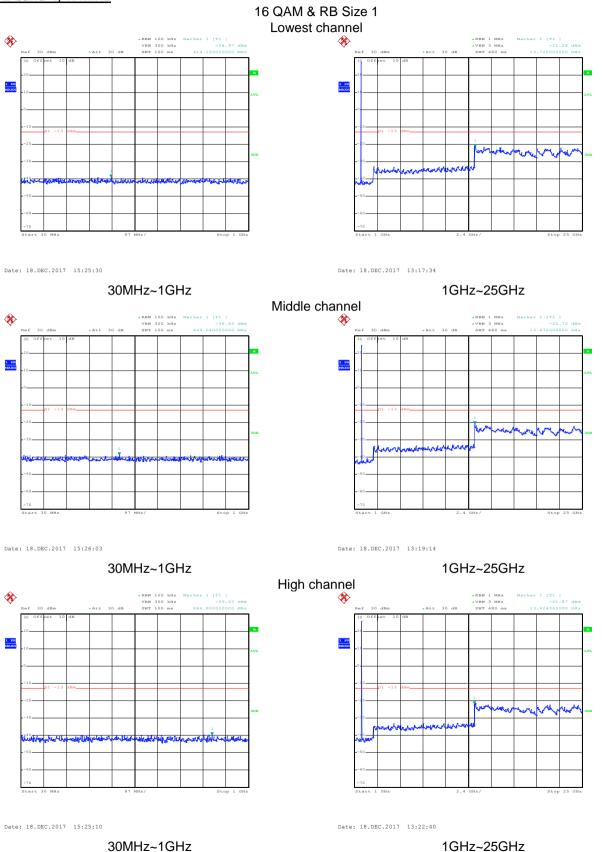
6.4 Out of band emission at antenna terminals

Test Requirement:	part 27.53(h)		
Test Method:	ANSI/TIA-603-D 2010		
Limit:	LTE Band 4: The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log ₁₀ (P) dB (-13 dBm).		
Test Setup:	System simulator Splitter ATT EUT		
	Spectrum Analyzer		
Test Procedure:	 The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation. The resolution bandwidth of the spectrum analyzer was set at 100 kHz when below 1GHz, 1MHz when above 1 GHz; sufficient scans were taken to show the out of band Emissions if any up to 10th harmonic. For the out of band: Set the RBW=100 kHz, VBW=300 kHz when below 1 GHz, RBW =1 MHz, VBW=3 MHz when above 1 GHz, Start=30MHz, Stop= 10th harmonic. Band Edge Requirements: In the 1 MHz bands immediately outside and adjacent to the frequency block, a resolution bandwidth of at least 1 percent of the emission bandwidth of the fundamental emission of the transmitter may be employed to measure the out of band Emissions. 		
Test Instruments:	Refer to section 5.9 for details		
Test mode:	Refer to section 5.3 for details		
Test results:	Passed		



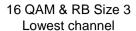


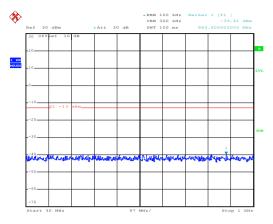
Test plots as follows: Conducted spurious emission LTE band 4, 1.4MHz

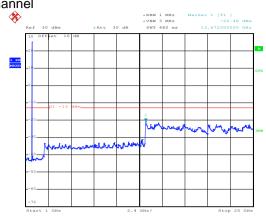












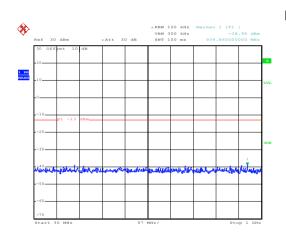
Date: 18.DEC.2017 15:26:54

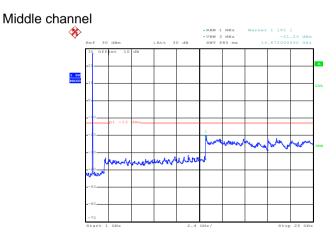
30MHz~1GHz

1GHz~25GHz

Date: 18.DEC.2017 13:18:06

Date: 18.DEC.2017 13:19:34

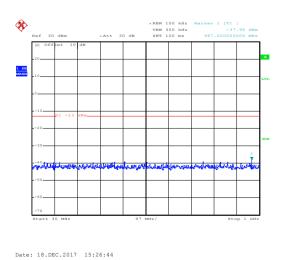


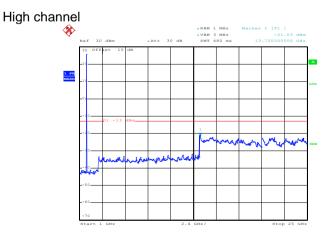


Date: 18.DEC.2017 15:26:17

 $30MHz\sim1GHz$

1GHz~25GHz





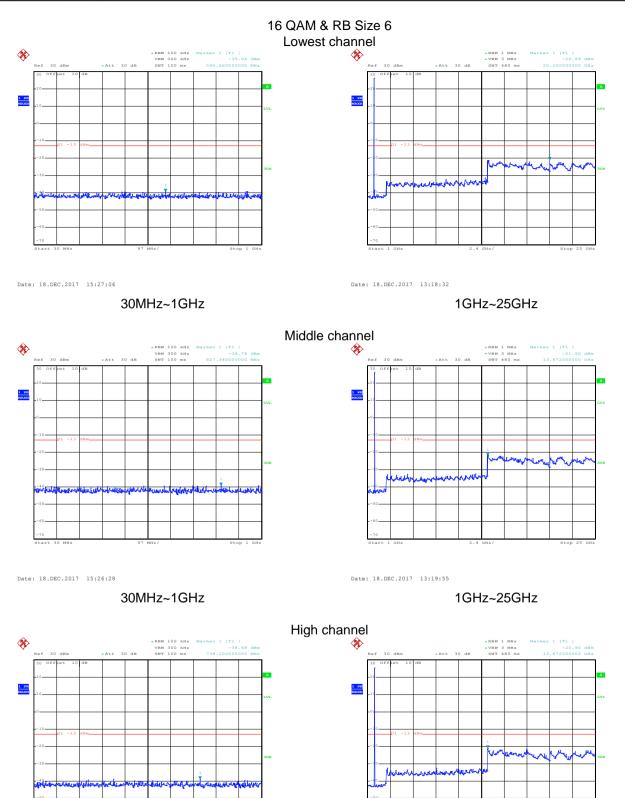
Date: 18.DEC.2017 13:23:04

30MHz~1GHz

1GHz~25GHz







Shenzhen Zhongjian Nanfang Testing Co., Ltd.

No. B-C, 1/F., Building 2, Laodong No.2 Industrial Park, Xixiang Road,

Project No.: CCISE1712069

Date: 18.DEC.2017 13:26:29

1GHz~25GHz

Bao'an District, Shenzhen, Guangdong, China

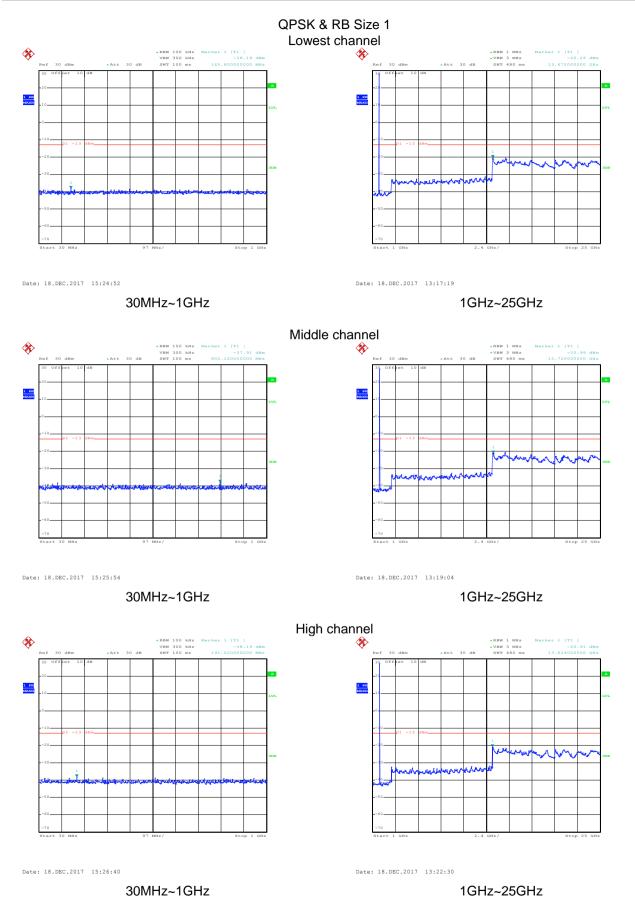
Date: 18.DEC.2017 15:25:43

Telephone: +86 (0) 755 23118282 Fax: +86 (0) 755 23116366

30MHz~1GHz

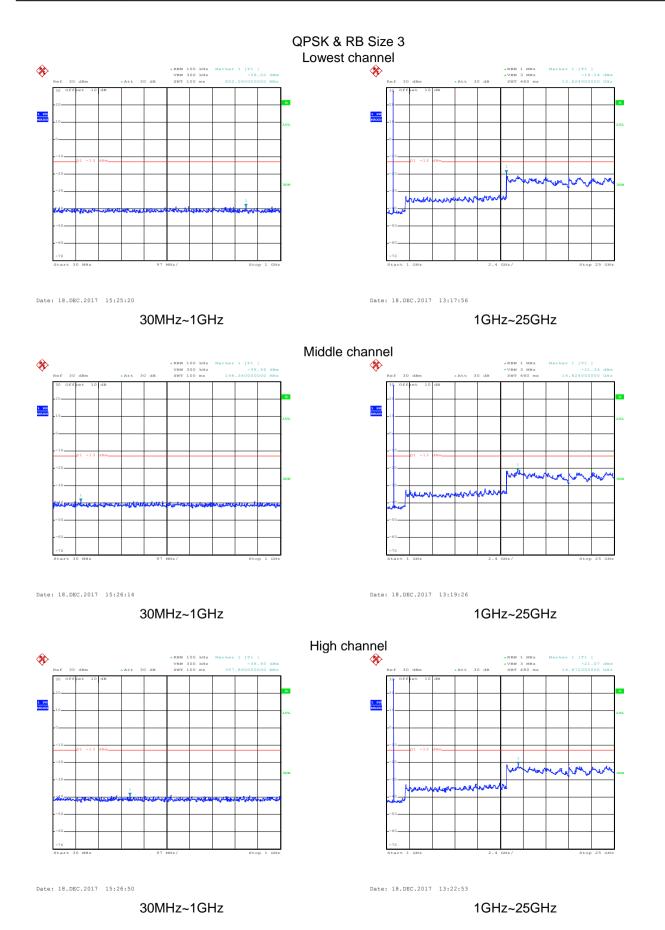






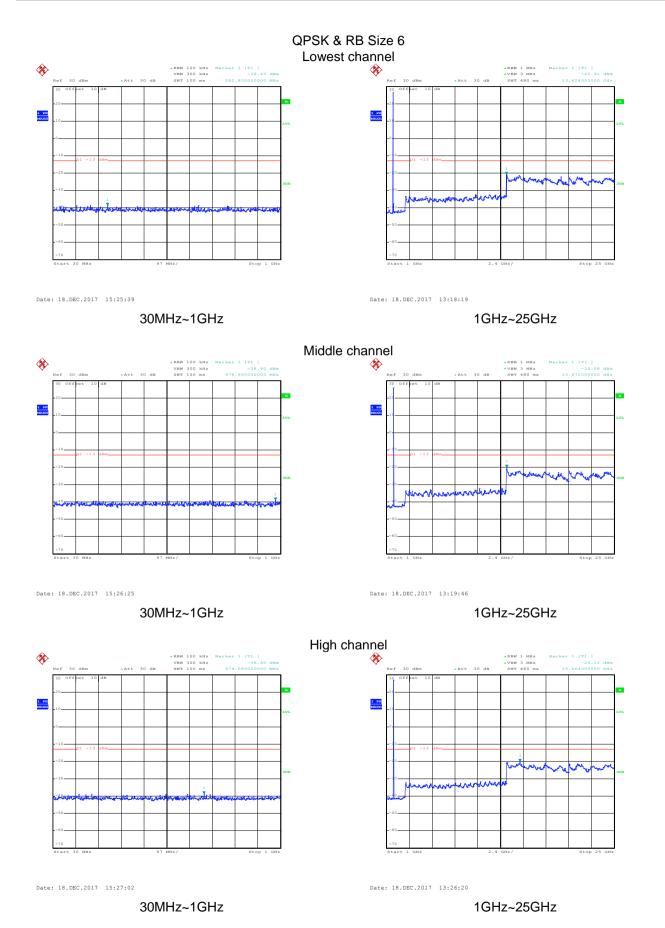








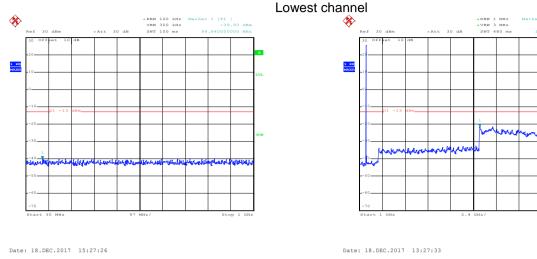






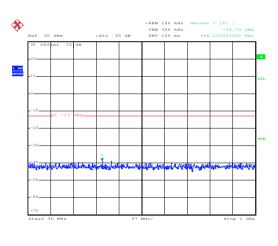
3MHz

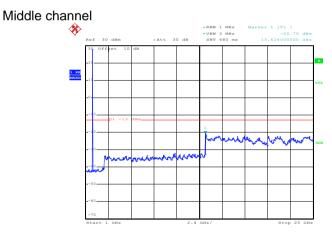
16 QAM & RB Size 1



30MHz~1GHz

1GHz~25GHz





1GHz~25GHz

Date: 18.DEC.2017 15:28:08

Date: 18.DEC.2017 15:29:00

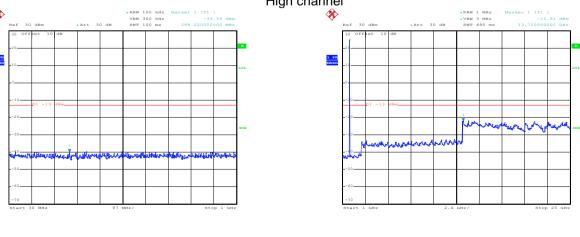
1

30MHz~1GHz

High channel

Date: 18.DEC.2017 13:29:08

Date: 18.DEC.2017 13:30:32

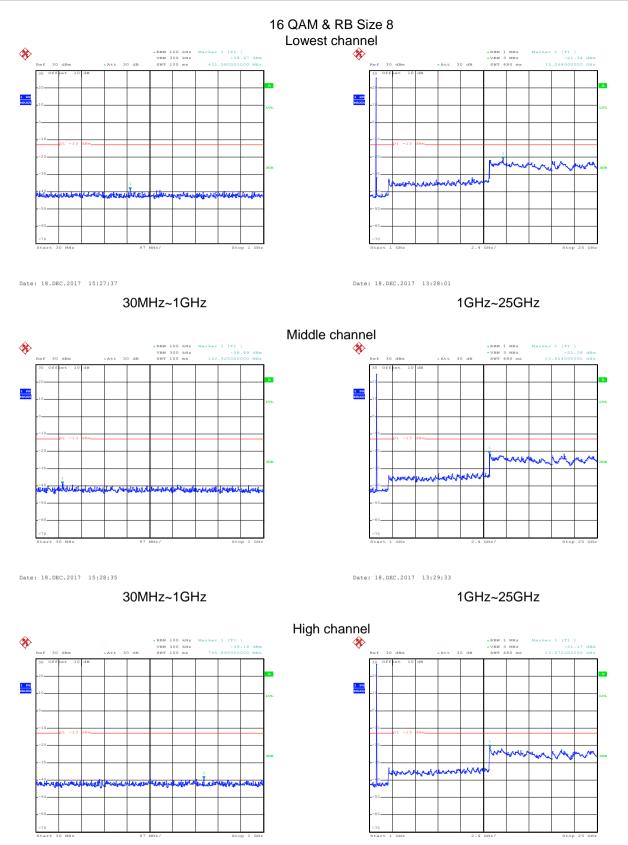


30MHz~1GHz

1GHz~25GHz







Date: 18.DEC.2017 13:31:01

1GHz~25GHz

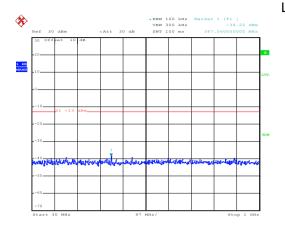
30MHz~1GHz

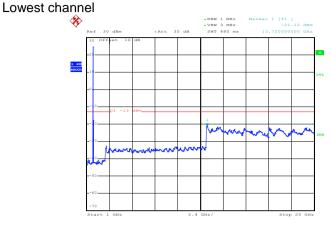
Date: 18.DEC.2017 15:29:11





16 QAM & RB Size 15





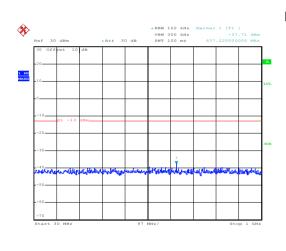
Date: 18.DEC.2017 15:27:52

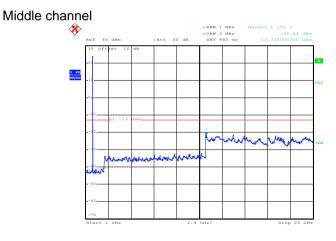
30MHz~1GHz

1GHz~25GHz

Date: 18.DEC.2017 13:28:20

Date: 18.DEC.2017 13:29:53

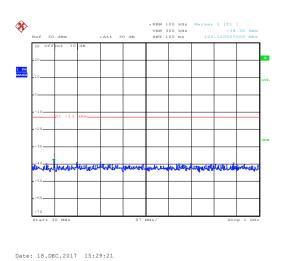


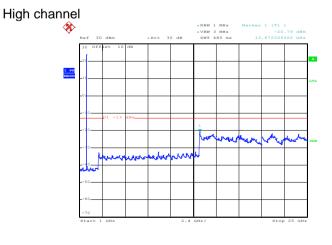


Date: 18.DEC.2017 15:28:47

30MHz~1GHz

1GHz~25GHz



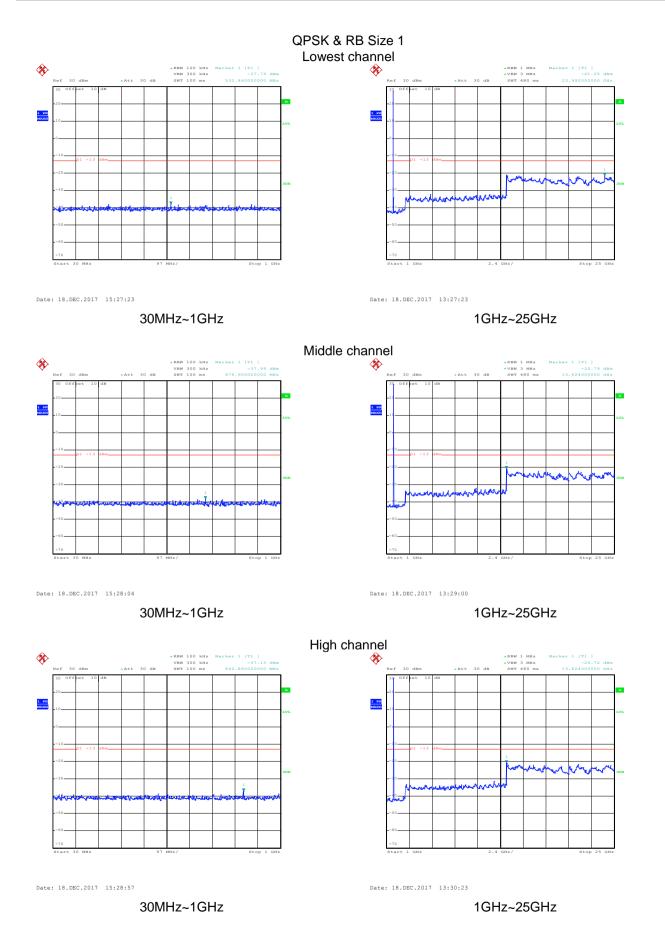


Date: 18.DEC.2017 13:31:19

30MHz~1GHz 1GHz~25GHz

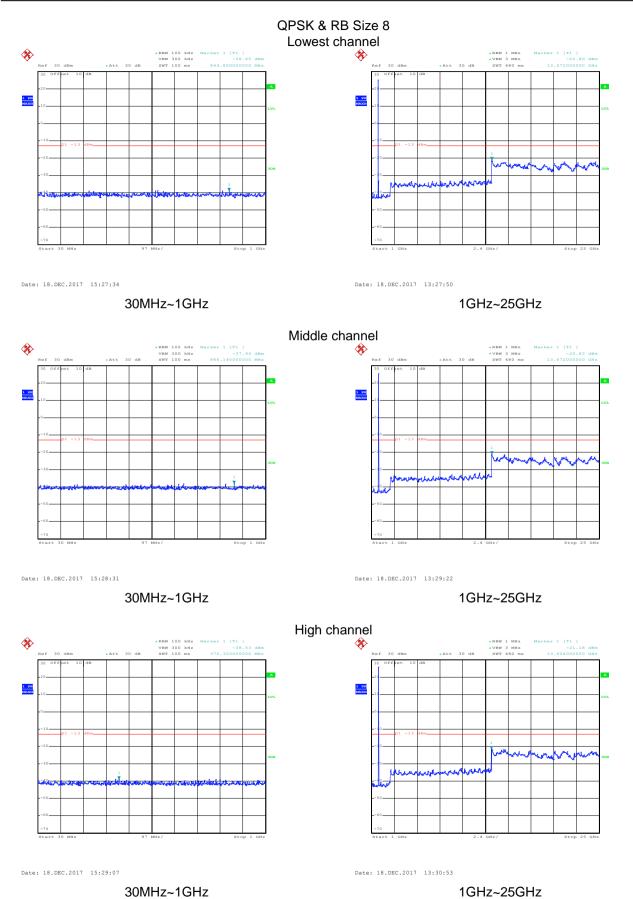






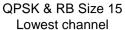


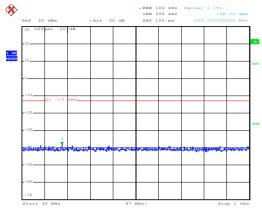


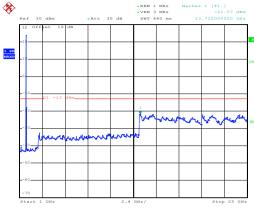








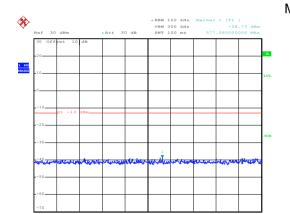


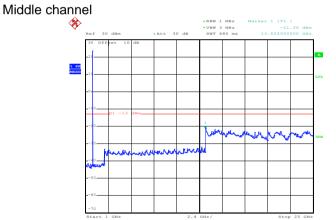


Date: 18.DEC.2017 15:27:49 30MHz~1GHz

Date: 18.DEC.2017 13:28:14

1GHz~25GHz



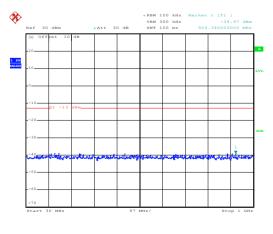


Date: 18.DEC.2017 15:28:43

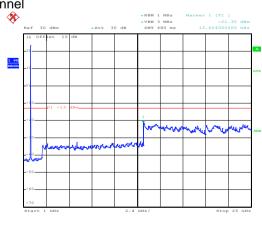
Date: 18.DEC.2017 15:29:18

Date: 18.DEC.2017 13:29:44

High channel



 $30MHz\sim1GHz$



1GHz~25GHz

Date: 18.DEC.2017 13:31:12

30MHz~1GHz

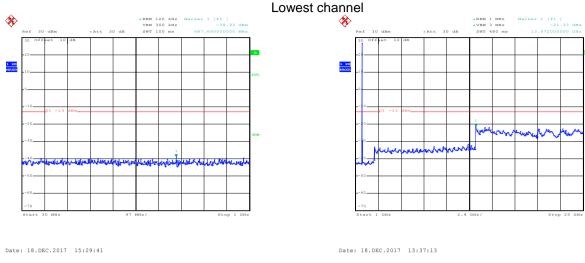
1GHz~25GHz





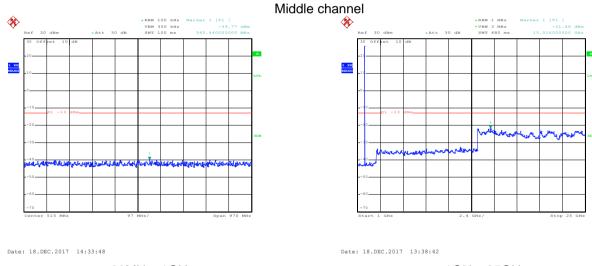
5MHz

16 QAM & RB Size 1



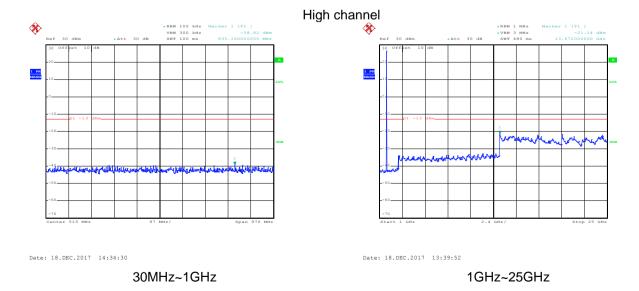
30MHz~1GHz

1GHz~25GHz



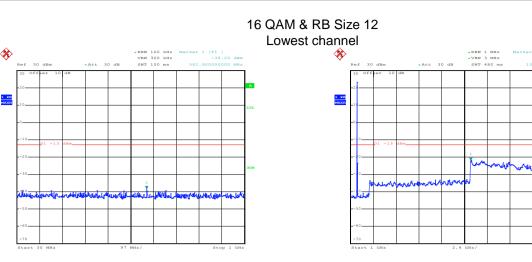


1GHz~25GHz





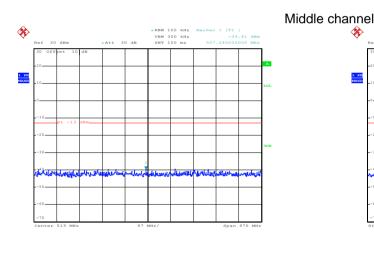




Date: 18.DEC.2017 15:29:51 30MHz~1GHz

Date: 18.DEC.2017 13:37:44

1GHz~25GHz

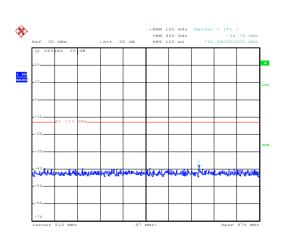


Date: 18.DEC.2017 14:34:02

Date: 18.DEC.2017 14:34:39

1GHz~25GHz

Date: 18.DEC.2017 13:39:05



30MHz~1GHz

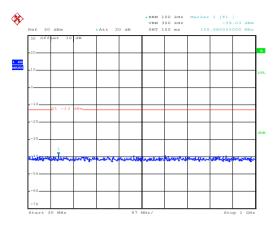
Date: 18.DEC.2017 13:40:14

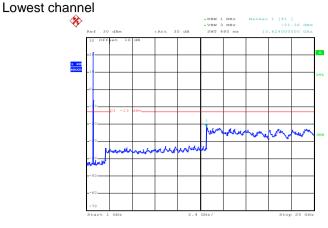
30MHz~1GHz 1GHz~25GHz





16 QAM & RB Size 25





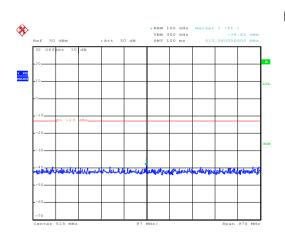
Date: 18.DEC.2017 15:29:48

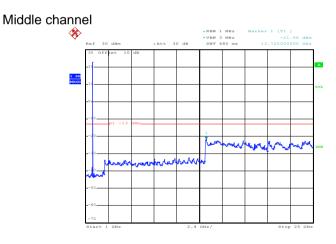
30MHz~1GHz

1GHz~25GHz

Date: 18.DEC.2017 13:38:06

Date: 18.DEC.2017 13:39:24

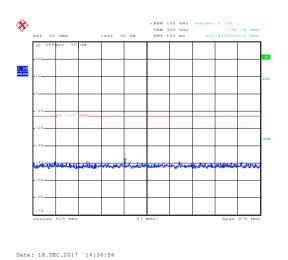


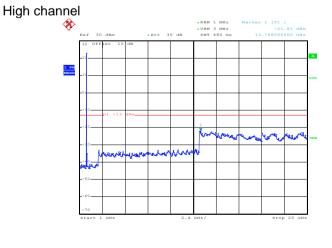


Date: 18.DEC.2017 14:34:14

 $30MHz\sim1GHz$

1GHz~25GHz





Date: 18.DEC.2017 13:40:35

30MHz~1GHz 1GHz~25GHz





